

To all our customers

Regarding the change of names mentioned in the document, such as Mitsubishi Electric and Mitsubishi XX, to Renesas Technology Corp.

The semiconductor operations of Hitachi and Mitsubishi Electric were transferred to Renesas Technology Corporation on April 1st 2003. These operations include microcomputer, logic, analog and discrete devices, and memory chips other than DRAMs (flash memory, SRAMs etc.) Accordingly, although Mitsubishi Electric, Mitsubishi Electric Corporation, Mitsubishi Semiconductors, and other Mitsubishi brand names are mentioned in the document, these names have in fact all been changed to Renesas Technology Corp. Thank you for your understanding. Except for our corporate trademark, logo and corporate statement, no changes whatsoever have been made to the contents of the document, and these changes do not constitute any alteration to the contents of the document itself.

Note : Mitsubishi Electric will continue the business operations of high frequency & optical devices and power devices.

Renesas Technology Corp.
Customer Support Dept.
April 1, 2003

M62293FP

3.3V, 2.5V FIXED 2-OUTPUT VOLTAGE DC-DC CONVERTER

DESCRIPTION

M62293FP is 3.3V and 2.5V fixed stable 2-output step-down DC-DC converter.

It is possible to simplify peripheral circuit and to design compact and low cost sets because this device includes peripheral devices in small size 8pin package.

The IC also has Reset circuit with time delay that monitors power supply($V_{cc}=5V$) and one regulator output($V_{out1}=3.3V$;IN1 terminal), therefore an application system is protected system errors.

Especially this is most suitable for application system with microprocessor and ASIC.

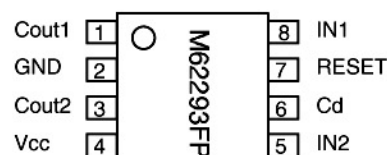
FEATURES

- 3.3V and 2.5V step-down converter
- 4 to 15V wide input supply voltage ($V_{cc}=5V$ typ.)
- Reset circuit with time delay monitors supply voltage($V_{cc}=5V$)and regulator output (3.3V)
- 110kHz fixed frequency oscillator without peripheral devices
- 8pin SOP package

APPLICATION

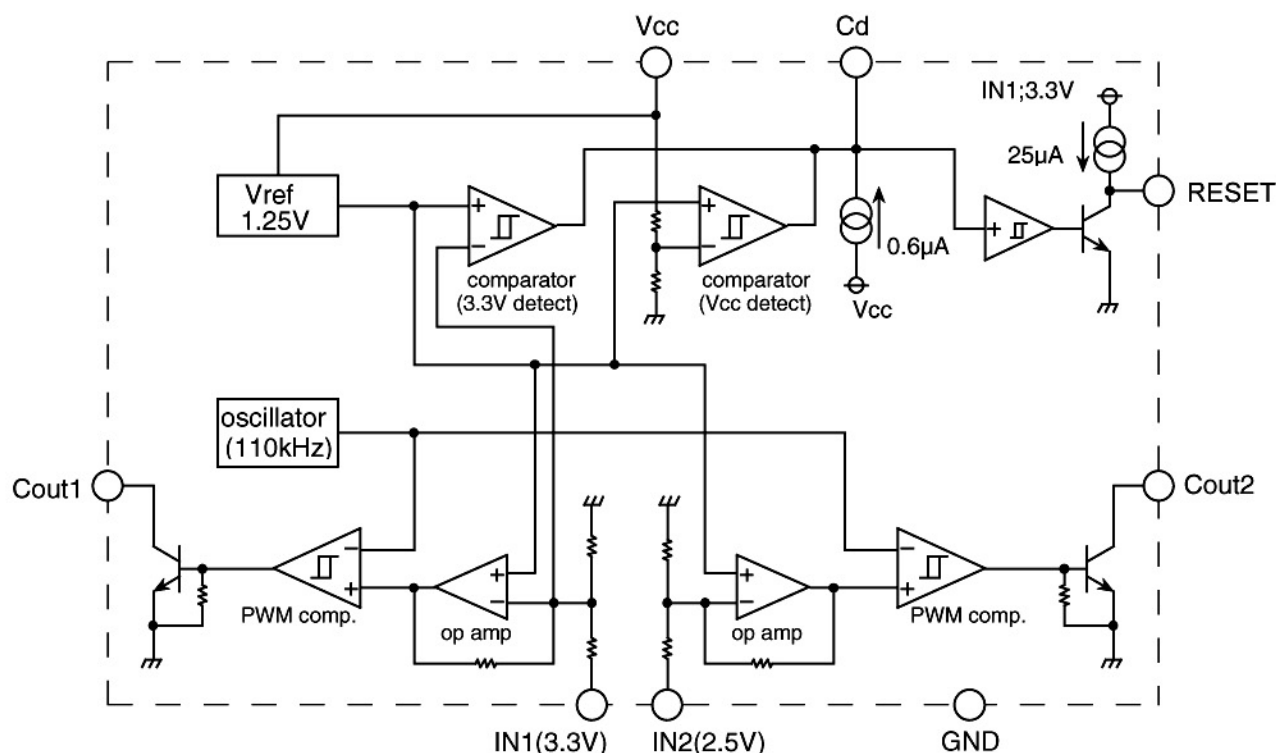
application system with microprocessor and ASIC

PIN CONFIGURATION(TOP VIEW)



Outline 8P2S-A

BLOCK DIAGRAM



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ABSOLUTE MAXIMUM RATINGS(Ta=25°C,unless otherwise noted)

Symbol	Parameter	Conditions	Ratings	Unit
Vcc	Supply voltage		16	V
Io	Output current(DC-DC converter block)	ch1,ch2	30	mA
IoRESET	Output current(Reset block)		6	mA
Pd	Power dissipation	Ta=25°C	440	mW
Kθ	Thermal derating	Ta>25°C	4.4	mW/°C
Topr	Operating temperature		-20~+85	°C
Tstg	Storage temperature		-40~+125	°C

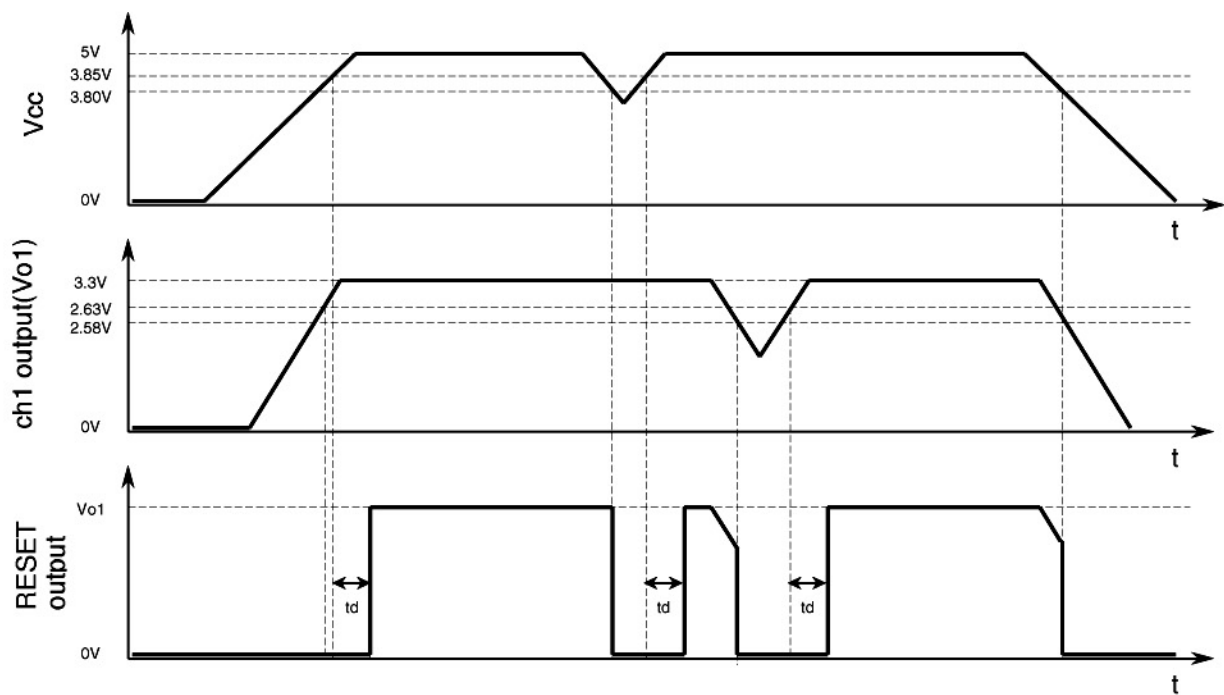
ELECTRICAL CHARACTERISTICS(Ta=25°C,Vcc=5V,unless otherwise noted)

Block	Symbol	Parameter	Test condition	Limits			Unit
				Min.	Typ.	Max.	
All Blocks	Vcc	Supply voltage		4.0	5.0	15	V
	Icc	Supply current	Without load	-	1.5	2.8	mA
DC-DC Converter Block							
Error Amp.	Vo1	Output voltage	ch1 output	3.15	3.30	3.45	V
	Vo2		ch2 output	2.37	2.50	2.63	
	Vreg-L	Line regulation	Vcc=4~12V	-	5	15	mV
	Iin	Input current 1	ch1	-	150	450	μA
	Iin	Input current 2	ch2	-	100	300	μA
Oscillator	fosc	Oscillator frequency		65	110	160	KHz
Output	TDUTY	Maximum ON duty		-	90	-	%
	ICL	Output leakage current	Vcc=12V, Vc=12V	-1	-	1	V
	Vsat	Output saturation voltage	Io=10mA,Darlington connection	-	1.2	2.0	V
Reset circuit Block							
Reset Circuit	Vs1	Detecting voltage 1	Vcc=5V detection	3.6	3.8	4.0	V
	ΔVs1	hysterisys voltage 1		30	50	80	mV
	Vs2	Detecting voltage 2	ch1output(3.3V)detection	2.46	2.58	2.70	V
	ΔVs2	Hysterisys voltage 2		30	50	80	mV
	IPD	Cd output current		-1.1	-0.6	-0.3	μA
	tpd	Delay time	Cd=4700pF	5	10	20	msec
	IOC	RESET output current	Vcc=5V, Vo=1/2 x Vcc	-40	-25	-17	μA
	VOL	RESET LOW voltage	IoRESET=4mA	-		0.2Vo1	V
	VOH	RESET High voltage		0.8Vo1		-	V

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RESET BLOCK timing chart



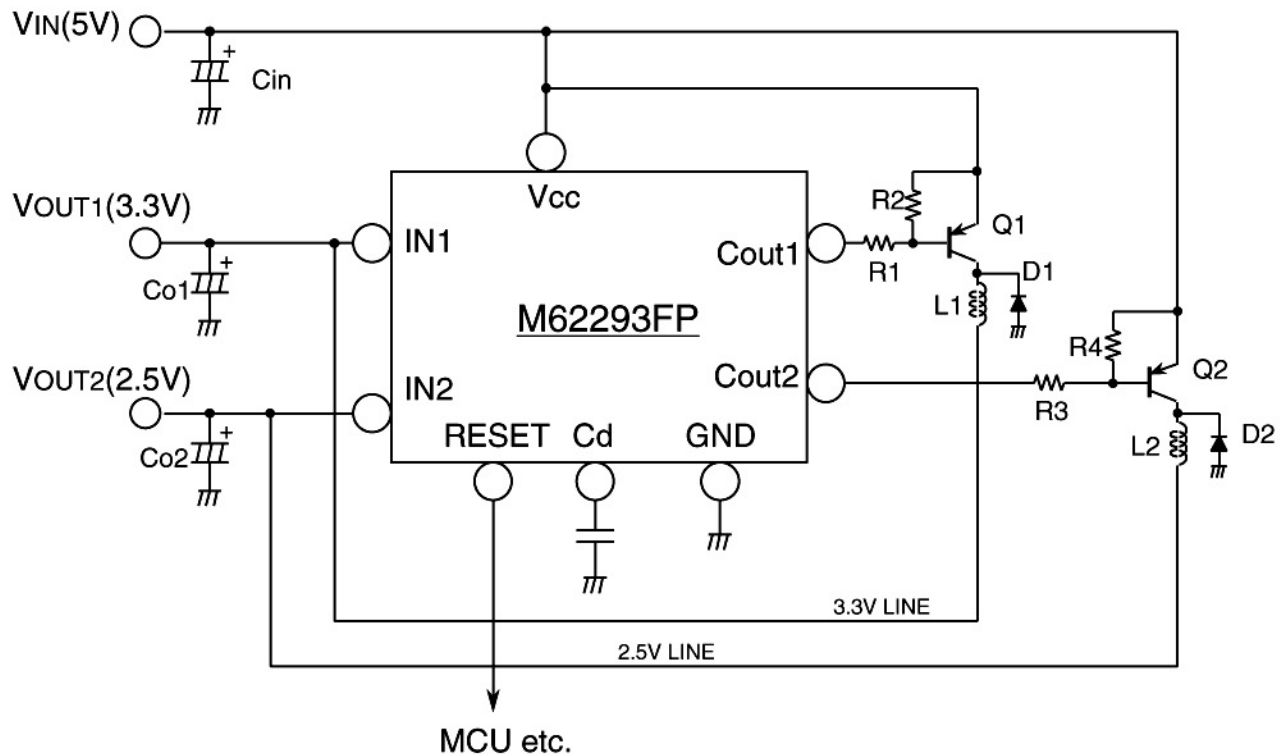
t_d : RESET Delay Time ***

$$t_d(\text{msec}) \approx 2.13 \times 10^{-3} \times C_d(\text{pF})$$

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APPLICATION CIRCUIT (3.3V and 2.5V 2-output voltage DC-DC converter)



THE EXPRESSION OF CIRCUIT CONSTANTS

Constants	Expressions
$\frac{TON}{TOFF}$	$\frac{VO+VF}{VIN - VCE(sat) - VO}$
$(TON+TOFF)MAX$	$\frac{1}{fosc} \quad fosc:110KHz(Vcc=5V)$
$TOFF(MIN)$	$(TON + TOFF) / (1 + \frac{TON}{TOFF})$
$TON(MAX)$	$\frac{1}{fosc} - TOFF$
$L(MIN)$	$\frac{(VIN - VCE(sat) - VO) \times TON(MAX)}{\Delta Io}$
Ipk	$Io + \frac{1}{2} \Delta Io$

note:

- VF : Forward voltage drop of an external diode
- Vsat : Output saturation voltage of an external switching transistor.
- ΔIo : Set to 1/3 to 1/5 of maximum output current.
- Choose an external transistor, diode and inductor with peak current rating approximately greater than "Ipk".